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Vishay Semiconductors

# Standard Recovery Diodes, (Stud Version), 85 A



DO-5 (DO-203AB)

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub> 85 A				
Package DO-5 (DO-203AB)				
Circuit configuration	Single			

#### **FEATURES**

- High surge current capability
- Stud cathode and stud anode version



- Leaded version available
- Types up to 1600 V V<sub>RRM</sub>
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

- · Battery chargers
- Converters
- Power supplies
- Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST COMPLETIONS	85H	IF(R)	LINUTO
	TEST CONDITIONS	10 to 120	140 to 160	UNITS
I <sub>F(AV)</sub>		85	85	Α
	T <sub>C</sub>	140	110	°C
I <sub>F(RMS)</sub>		133	133	Α
I <sub>FSM</sub>	50 Hz	1700	1700	٨
	60 Hz	1800	1800	Α
l²t	50 Hz	14 500	14 500	A <sup>2</sup> s
	60 Hz	13 500	13 500	A <sup>2</sup> S
$V_{RRM}$	Range	100 to 1200	1400 to 1600	V
T <sub>J</sub>		-65 to +180	-65 to +150	°C

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$\begin{array}{c} I_{RRM} \text{ MAXIMUM} \\ \text{AT T}_J = T_J \text{ MAXIMUM} \\ \text{mA} \end{array}$	
	10	100	200		
	20	200	300		
VS-85HF(R) VS-86HF(R) VS-87HF(R) VS-88HF(R) 100 120 140	40	400	500		
	60	600	700	9	
	80	800	900		
	100	1000	1100		
	120	1200	1300		
	140	1400	1500	4.5	
	160	1600	1700	4.5	



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FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS		85HF(R)		LINUTO		
PANAMETEN	STIVIBUL		TEST CONDITIONS			140/160	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	180° condu	180° conduction, half sine wave		8	5	Α	
at case temperature	·F(AV)	100 00.100			140	110	°C	
Maximum RMS forward current	I <sub>F(RMS)</sub>				133		Α	
		t = 10 ms	No voltage		1700		A	
Maximum peak, one-cycle forward,	l-a	t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	1800			
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		1450			
		t = 8.3  ms	reapplied		1500			
	l <sup>2</sup> t	t = 10 ms	No voltage reapplied		14 500		- A <sup>2</sup> s	
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms			13 500			
Maximum i-t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		10 500			
		t = 8.3 ms	reapplied		9400			
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied		16	000	A²√s		
Value of threshold voltage (up to 1200 V)	- V <sub>F(TO)</sub>	V	V	T T		0.	68	V
Value of threshold voltage (for 1400 V, 1600 V)		$T_J = T_J$ maximum		0.	69	ľ		
Value of forward slope resistance (up to 1200 V)	, .	$T_J = T_J$ maximum		T - T movimum	1.62		- mW	
Value of forward slope resistance (for 1400 V, 1600 V)	- r <sub>f</sub>			1.			11100	
Maximum forward voltage drop	$V_{FM}$	$I_{pk} = 267 A$	$T_J = 25  ^{\circ}C, t_p =$	= 400 µs rectangular wave	1.2	1.4	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
DADAMETED	PARAMETER SYMBOL TEST	TEGT COMPLETIONS	85H		
PARAMETER		TEST CONDITIONS	10 to 20	140 to 160	UNITS
Maximum junction operating and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +180	-65 to +150	°C
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	0.	0.35	
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.	0.25	
Maximum shock (1)			15	1500	
Maximum constant vibration (1)		50 Hz	2	20	
Maximum constant acceleration (1)		Stud outwards	5000		
		Not lubricated thread, tighting on nut	3.4 (30)		
Maximum allowable mounting torque		Lubricated thread, tighting on nut	2.3 (20) 4.2 (37)		N ⋅ m (lbf ⋅ in)
+ 0 %, - 10 %		Not lubricated thread, tighting on hexagon			
		Lubricated thread, tighting on hexagon	3.2	(28)	
Approximate weight		Unleaded device	1	7	g
Approximate weight		Officaucu device	0	0.6	
Case style		See dimensions - link at the end of datasheet	DO-5 (DO-203AB)		)

#### Notes

- (1) Available only for 88HF
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

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△R <sub>thJC</sub> CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.10	0.08			
120°	0.11	0.11			
90°	0.13	0.13	$T_J = T_J$ maximum	K/W	
60°	0.17	0.17			
30°	0.26	0.26			

#### Note

The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

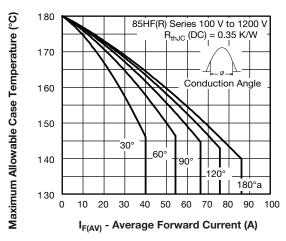


Fig. 1 - Current Ratings Characteristics

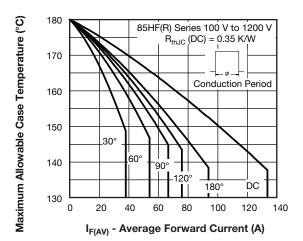


Fig. 2 - Current Ratings Characteristics

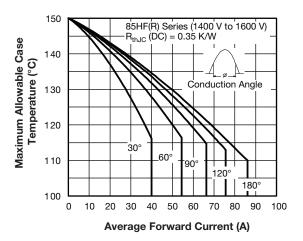


Fig. 3 - Current Ratings Characteristics

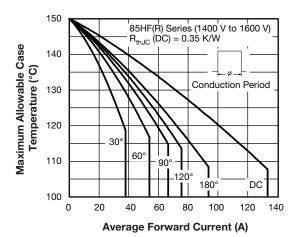


Fig. 4 - Current Ratings Characteristics

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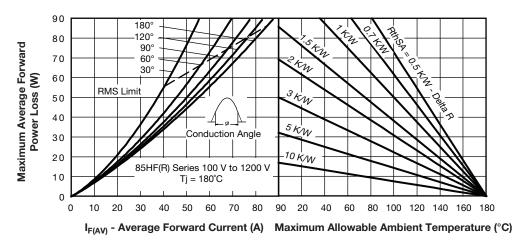


Fig. 5 - Forward Power Loss Characteristics

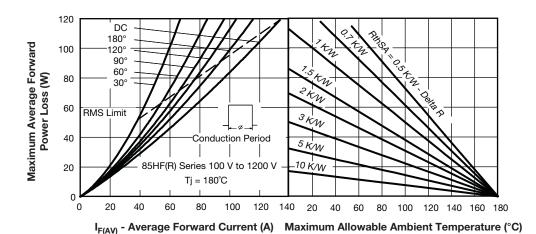


Fig. 6 - Forward Power Loss Characteristics

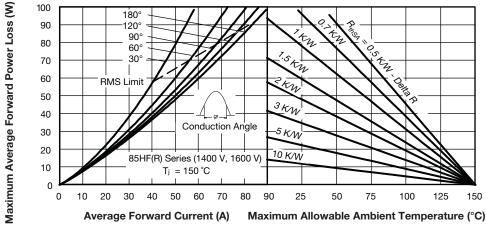


Fig. 7 - Forward Power Loss Characteristics

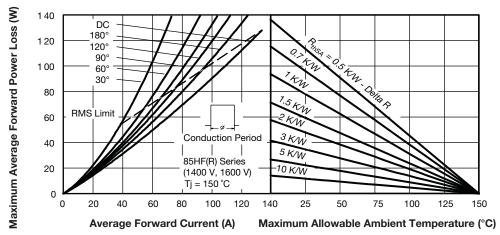


Fig. 8 - Forward Power Loss Characteristics

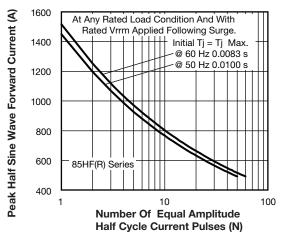


Fig. 9 - Maximum Non-Repetitive Surge Current

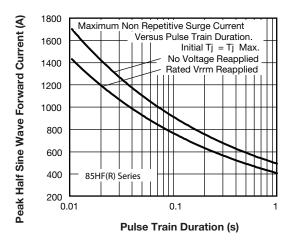


Fig. 10 - Maximum Non-Repetitive Surge Current

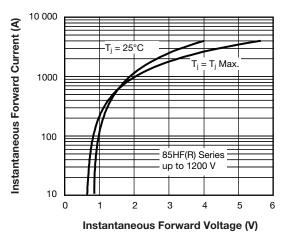


Fig. 11 - Forward Voltage Drop Characteristics

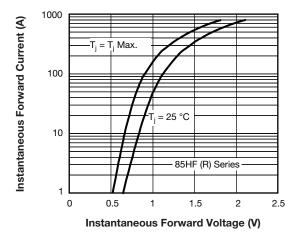


Fig. 12 - Forward Voltage Drop Characteristics (for 1400 V, 1600 V)

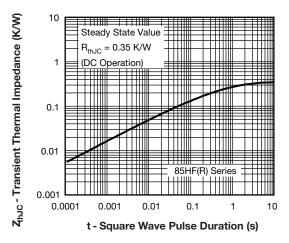
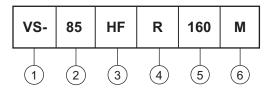


Fig. 13 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**





1 - Vishay Semiconductors product

2 - 85 = standard device

86 = not isolated lead

87 = isolated lead with silicone sleeve

(red = Reverse polarity)

(blue = Normal polarity)

88 = type for rotating application

3 - HF = standard diode

4 - None = stud normal polarity (cathode to stud)

R = stud reverse polarity (anode to stud)

5 - Voltage code x 10 = V<sub>RRM</sub> (see Voltage Ratings table)

None = stud base DO-5 (DO-203AB) 1/4" 28UNF-2A
M = stud base DO-5 (DO-203AB) M6 x 1 (not available for 88HF)

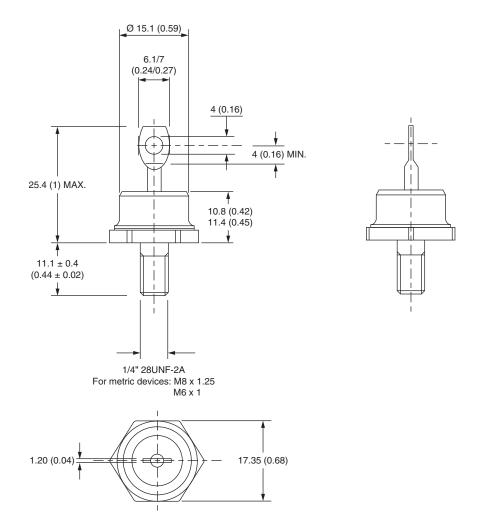
M8 = stud base DO-5 (DO-203AB) M8 x 1.25 (not available for 88HF)

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95342		

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# DO-5 (DO-203AB) for 85HF(R), 86HF(R) and 88HF(R)Series

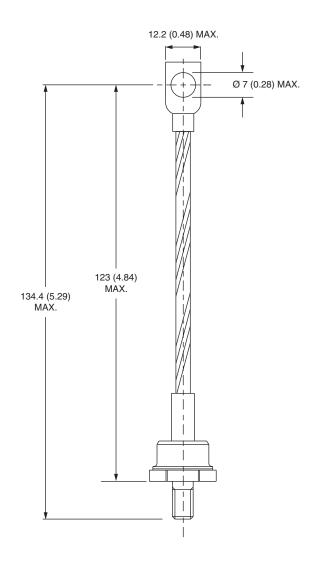
### **DIMENSIONS FOR 85HF(R) SERIES** in millimeters (inches)





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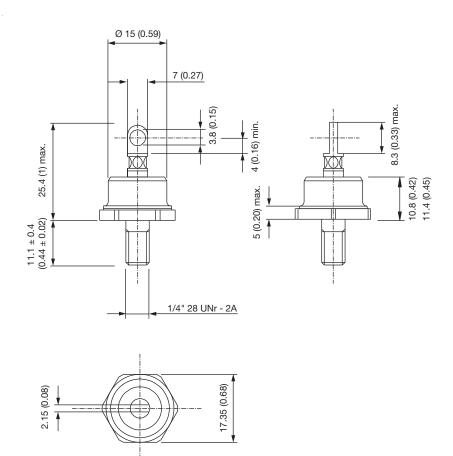
#### **DIMENSIONS FOR 86HF(R) SERIES** in millimeters (inches)





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#### **DIMENSIONS 88HF(R) SERIES** in millimeters (inches)





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